NSN 5961-01-014-0524

Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-014-0524 **Inclosure Material:** Ceramic or glass or metal **Overall Length:** Between 0.685 inches and 0.715 inches **Terminal Length:** 0.100 inches **Overall Height:** 0.145 inches **Overall Width:** Between 0.220 inches and 0.280 inches **Component Name And Quantity:** 4 transistor **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon all transistor Voltage Rating In Volts Per Characteristic: 70.0 collector to base voltage/static/emitter open all transistor and 40.0 collector to emitter voltage/static/base open all transistor and 6.0 emitter to base voltage, static, collector open all transistor **Power Rating Per Characteristic:** 1.5 watts small-signal input power, common-collector preset all transistor **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction and 125.0 degrees celsius ambient air **Special Features:** All transistor junction pattern arrangement: npn **Test Data Document:** 30003-247as-c0932 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 14 pin Shelf Life: N/a **Unit Of Measure:**

Demilitarization:

No

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